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PATENT Customer No. 22,852 Attorney Docket No. 04329.2613

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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OIPE OF	In re Application of:)		TEC	_	
WEELCE MICE I NAW	Katsuhiko HIEDA) Group A	Art Unit: 2814	Hack	AEC PAEC	
TRADEMARK	Serial No.: 09/916,509) Examin	er: T. Le	250	RECEIVED APR 15 2002	
HAUD	Filed: J	uly 30, 2001)		C. 18.	高昌日	
	N	EMICONDUCTOR DE METHOD FOR MANUF HE SAME		. ,		TECHNOLDON CENTER	2800	
	Commissioner for Patents Washington, DC 20231							
	Sir:							
	TRANSMITTAL LETTER							
	Enclosed is a reply to the Office Action of March 11, 2002. The items checked below are appropriate:							
	Applicant hereby petitions for a month extension of time to respond to the above Office Action. The fee of \$ for the Extension is enclosed.							
	The claims are calculated below:							
		Claims Remaining After Amendment		Highest Number Previously Paid	Present Extra	Rate	Additional Fee	
;	Total	45	-	43	2	x \$ 18	\$ 36.00	
	Inden	19	_	19	0	x \$ 84	0.00	

FINNEGAN HENDERSON FARABOW GARRETT& DUNNER LLP

1300 I Street, NW Washington, DC 20005 202.408.4000 Fax 202.408.4400 www.finnegan.com

A fee of \$36 to cover the cost of the additional claims added by this reply is enclo	
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A fee of \$ to cover is enclosed.

A check for \$36 to cover the above fee is enclosed.

First Presentation of Multiple Dep. Claim(s)

Please grant any extensions of time required to enter this response and charge any additional required fees to our deposit account 06-0916.

Dated: April 11, 2002

By: <u>By</u> S. Latham Reg. No. 49,085

FINNEGAN HENDERSON FARABOW GARRETT & DUNNER LLP

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PATENT Customer No. 22,852 Attorney Docket No. 04329.2613

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: 2814

Examiner: T. Le

In re Application of:

Katsuhiko HIEDA

Serial No.: 09/916,509

Filed: July 30, 2001

SEMICONDUCTOR DEVICE AND For: METHOD FOR MANUFACTURING THE SAME

Assistant Commissioner for Patents Washington, DC 20231

36.00 OP

Sir:

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AMENDMENT AND RESPONSE TO **ELECTION REQUIREMENT**

Please amend the application as follows:

IN THE CLAIMS:

Please amend claim 20 and add new claims 44 and 45 as follows:

20. (Amended) The method according to claim 19, wherein the convex semiconductor layer is formed with the epitaxial growth method.

HENDERSON FARABOW GARRETT&

1300 l Street, NW 202.408.4000 Fax 202.408.4400 finnegan.com

Washington, DC 20005

DUNNER LL

--44. (New) The device according to claim 1, wherein a position of a deepest portion of the gate electrode is deeper than a position of a deepest portion of the source region and a position of a deepest portion of the drain region.